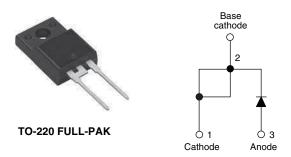


## VS-10ETF1...FPPbF Series, VS-10ETF1...FP-M3 Series

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# Fast Soft Recovery Rectifier Diode, 10 A



PRODUCT SUMMARY				
Package	TO-220FP			
I <sub>F(AV)</sub>	10 A			
V <sub>R</sub>	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.33 V			
I <sub>FSM</sub>	185 A			
t <sub>rr</sub>	80 ns			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
Snap factor	0.6			

#### **FEATURES**

- 150 °C max. operation junction temperature
- Designed and qualified according t JEDEC-JESD47
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL E78996 approved
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 defintion (-M3 only)





ROHS COMPLIANT HALOGEN FREE

### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

#### **DESCRIPTION**

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V <sub>RRM</sub>		1000 to 1200	V			
I <sub>F(AV)</sub>	Sinusoidal waveform	10	۸			
I <sub>FSM</sub>		160	A A			
t <sub>rr</sub>	1 A, 100 A/μs	80	ns			
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.33	V			
T <sub>J</sub>		- 40 to 150	°C			

VOLTAGE RATINGS					
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA		
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4		
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	4		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 95 °C, 180° conduction half sine wave	10	
Maximum peak one cycle	1	10 ms sine pulse, rated V <sub>RRM</sub> applied	160	Α
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	185	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	128	A <sup>2</sup> s
	1-1	10 ms sine pulse, no voltage reapplied	180	A-S
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied	1800	A <sup>2</sup> √s



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	10 A, T <sub>J</sub> = 25 °C		1.33	V
Forward slope resistance	r <sub>t</sub>	- T <sub>J</sub> = 150 °C		22.9	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.96	V
Maximum rayaraa laakaga aurrant	1	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR = nated VRRM	4	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> at 10 Apk	310	ns	I <sub>FM</sub>
Reverse recovery current	I <sub>rr</sub>	25 Α/μs	4.7	Α	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Reverse recovery charge	Q <sub>rr</sub>	25 °C	1.05	μC	dir/ dt Q.,
Snap factor	S		0.6		LDM/DEC/

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	rage	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resistan junction to case	ce	$R_{thJC}$	DC operation	2.5	
Maximum thermal resistance junction to ambient		R <sub>thJA</sub>		62	°C/W
Typical thermal resistance case to heatsink	,	R <sub>thCS</sub>	Mounting surface, smooth and greased 0.8		
A consistence to the second to be				2	g
Approximate weight	Approximate weight			0.07	oz.
Mounting torque -	minimum			6 (5)	kgf ⋅ cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220 FULL-PAK	10ETF10FP 10ETF12FP	

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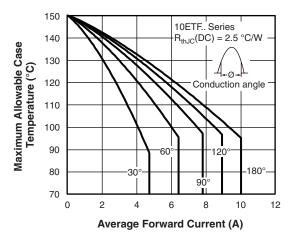


Fig. 1 - Current Rating Characteristics

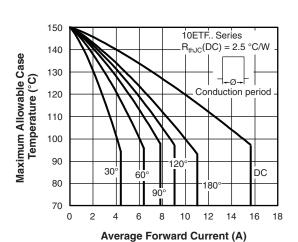


Fig. 2 - Current Rating Characteristics

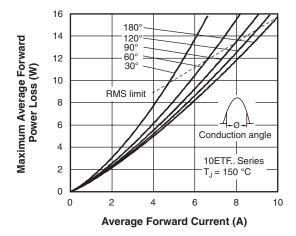


Fig. 3 - Forward Power Loss Characteristics

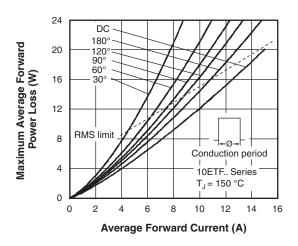
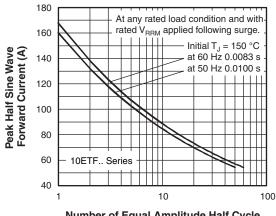


Fig. 4 - Forward Power Loss Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

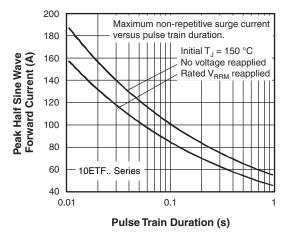


Fig. 6 - Maximum Non-Repetitive Surge Current

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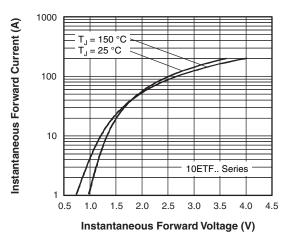


Fig. 7 - Forward Voltage Drop Characteristics

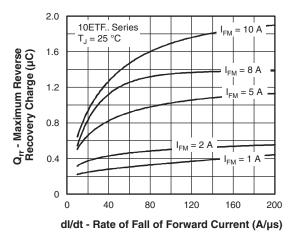


Fig. 10 - Recovery Charge Characteristics, T<sub>.I</sub> = 25 °C

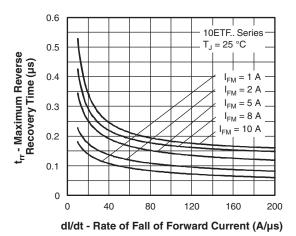


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

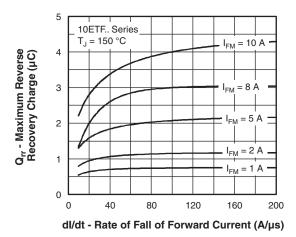


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C

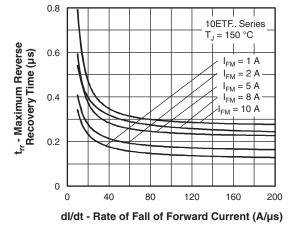
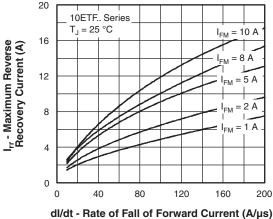


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C



di/dt - nate of rail of rollward current (A/μs)

Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

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# VS-10ETF1...FPPbF Series, VS-10ETF1...FP-M3 Series

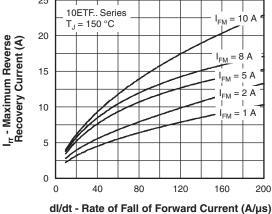


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

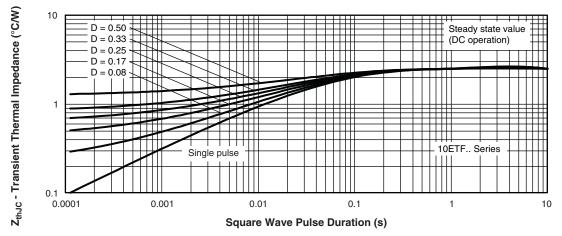


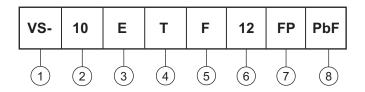
Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

## VS-10ETF1...FPPbF Series, VS-10ETF1...FP-M3 Series

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#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

Current rating (10 = 10 A)

Circuit configuration:

E = Single diode

Package:

T = TO-220

Type of silicon:

F = Fast soft recovery rectifier

02 = 200 V Voltage code x  $100 = V_{RRM}$ 04 = 400 V 06 = 600 V

**FULL-PAK** 

Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

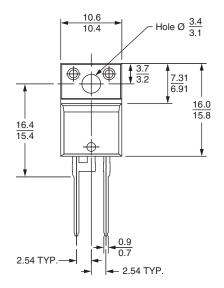
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

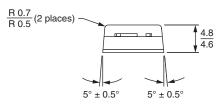
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Part marking information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		

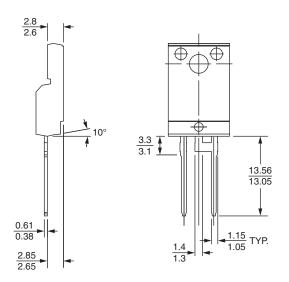


## Vishay Semiconductors

### **DIMENSIONS** in millimeters







#### Lead assignments

<u>Diodes</u>

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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